

SUPER FAST RECTIFIERS

VOLTAGE RANGE: 50 --- 600 V
CURRENT: 2.0 A

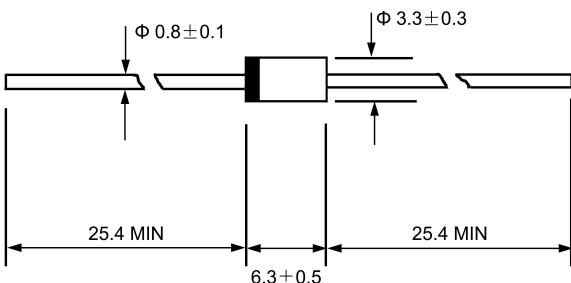
FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-15, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any

DO - 15



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

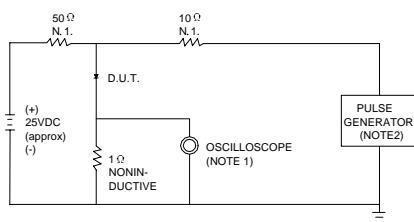
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SF21	SF22	SF23	SF24	SF25	SF26	SF27	SF28	UNITS				
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	V				
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	350	420	V				
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V				
Maximum average forward rectified current 9.5mm lead length, $\text{@ } T_A = 75^\circ\text{C}$	$I_{F(AV)}$	2.0							A					
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $\text{@ } T_J = 125^\circ\text{C}$	I_{FSM}	50							A					
Maximum instantaneous forward voltage $\text{@ } 2.0\text{A}$	V_F	0.95			1.25		1.7		V					
Maximum reverse current $\text{@ } T_A = 25^\circ\text{C}$ at rated DC blocking voltage $\text{@ } T_A = 125^\circ\text{C}$	I_R	5.0 50.0							μA					
Maximum reverse recovery time (Note1)	t_{rr}	35							ns					
Typical junction capacitance (Note2)	C_J	60			30		pF							
Typical thermal resistance (Note3)	$R_{\theta JA}$	20							$^\circ\text{C/W}$					
Operating junction temperature range	T_J	- 55 ----- + 125							$^\circ\text{C}$					
Storage temperature range	T_{STG}	- 55 ----- + 150							$^\circ\text{C}$					

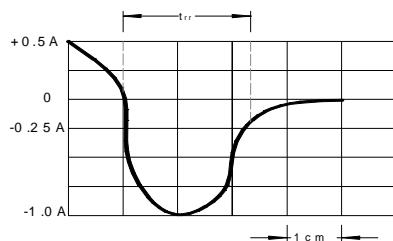
NOTE: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $I_{rr} = 0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

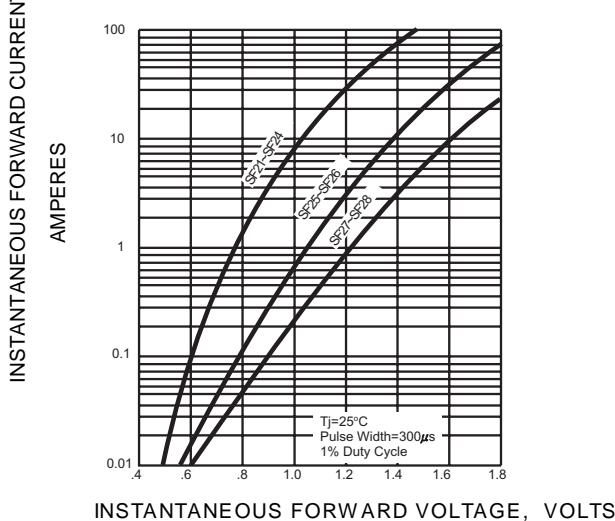
3. Thermal resistance from junction to ambient.

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

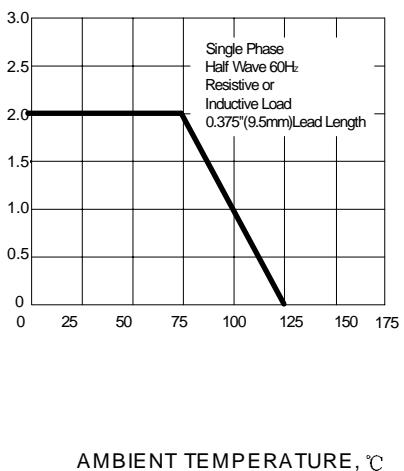
NOTES:
1. RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2. RISE TIME = 10ns MAX.SOURCE IMPEDANCE=50Ω.



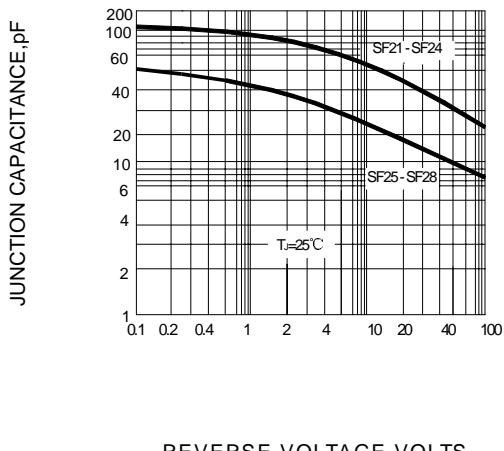
SET TIME BASE FOR 10 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

INSTANTANEOUS FORWARD CURRENT
AMPERES

FIG.3 -- FORWARD DERATING CURVE

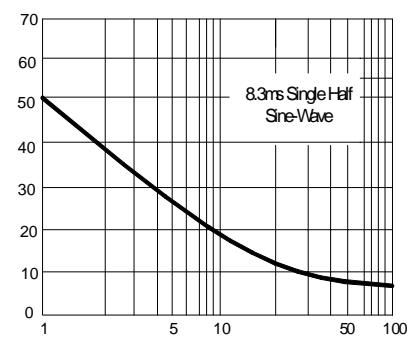
AMBIENT TEMPERATURE, °C

FIG.4 -- TYPICAL JUNCTION CAPACITANCE

JUNCTION CAPACITANCE,pF

REVERSE VOLTAGE, VOLTS

PEAK FORWARD SURGE CURRENT
AMPERES

FIG.5 -- PEAK FORWARD SURGE CURRENT

NUMBER OF CYCLES AT 60Hz